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|  | <p>SI1913EDH-T1-E3</p> |
| | <p>Hersteller-Teilenummer: SI1913EDH-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2P-CH 20V 0.88A SC70-6</p> <p>Datenblätter:  SI1913EDH-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 6525 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

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|--|---|
| Teilenummer | SI1913EDH-T1-E3 |
| Hersteller | Vishay / Siliconix |
| Beschreibung | MOSFET 2P-CH 20V 0.88A SC70-6 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs , |
| Teilstatus | 6525 pcs Stock |
| Serie | TrenchFET® |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Leistung - max | 570mW |
| Verpackung / Gehäuse | 6-TSSOP, SC-88, SOT-363 |
| Supplier Device-Gehäuse | SC-70-6 (SOT-363) |
| Typ FET | 2 P-Channel (Dual) |
| FET-Merkmal | Logic Level Gate |
| Drain-Source-Spannung (Vdss) | 20V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 880mA |
| Rds On (Max) @ Id, Vgs | 490 mOhm @ 880mA, 4.5V |
| VGS (th) (Max) @ Id | 450mV @ 100µA |
| Gate Charge (Qg) (Max) @ Vgs | 1.8nC @ 4.5V |
| Eingabekapazität (Ciss) (Max) @ Vds | - |
| Verpackung | Tape & Reel (TR) |






SI1913EDH-T1-E3 ist neu im Original. Suche SI1913EDH-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1913EDH-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1913EDH-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

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|---|--|--|---|
|  <p>SI1917EDH-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 12V 1A SC70-6</p> |  <p>SI1917EDH-T1-E3 Vishay / Siliconix MOSFET 2P-CH 12V 1A SC70-6</p> |  <p>SI1917EDH Vishay Precision Group SI1917EDH VISHAY</p> |  <p>SI1913EDH-T1 VISHAY SI1913EDH-T1 VISHAY</p> |
|  <p>SI1913DH-T1-GE3 Vishay Precision Group SI1913DH-T1-GE3 VISHAY</p> |  <p>SI1913EDH-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 0.88A SC70-6</p> |  <p>SI1913DH-T1-E3 Vishay / Siliconix MOSFET 2P-CH 20V 0.88A SC70-6</p> |  <p>SI1913DH-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 0.88A SC70-6</p> |

heiße Teile

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|  SI1903DL-T1-E3 |  SI1903DL-T1-GE3 |  SI1903DL-T1-GE3 |  SI1904EDH-T1 |  SI1904EDH-T1-GE3 |
|  SI1905BDH-T1-E3 |  SI1905BDH-T1-E3 |  SI1905BDH-T1-GE3 |  SI1905BDH-T1-E3 |  SI1905DL |
|  SI1905DL-T1 |  SI1905DL-T1-E3 |  SI1905DL-T1-E3 |  SI1905DL-T1-GE3 |  SI1906DL-T1 |
|  SI1912EDH |  SI1912EDH-T1 |  SI1912EDH-T1-E3 |  SI1912EDH-T1-E3 |  SI1912EDH-T1-GE3 |
|  SI1913DH-T1-E3 |  SI1913DH-T1-E3 |  SI1913DH-T1-GE3 |  SI1913EDH-T1 |  SI1913EDH-T1-E3 |
|  SI1913EDH-T1-GE3 |  SI1917EDH-T1 |  SI1917EDH-T1-E3 |  SI1917EDH-T1-E3 |  SI1917EDH-T1-GE3 |
|  SI1922EDH-T1-GE3 |  SI1922EDH-T1-GE3 |  SI1926DL-T1-E3 |  SI1926DL-T1-E3 |  SI1926DL-T1-GE3 |
|  SI1926DL-T1-GE3 |  SI1958DH-T1-E3 |  SI1958DH-T1-E3 |  SI1965DH-E3 |  SI1965DH-T1-E3 |
|  SI1965DH-T1-E3 |  SI1965DH-T1-GE3 |  SI1965DH-T1-GE3 |  SI1967DH-T1-E3 |  SI1967DH-T1-E3 |
|  SI1967DH-T1-GE3 |  SI1967DH-T1-GE3 |  SI1969DH-E3 |  SI1970DH-T1-GE3 |  SI1970DH-T1-GE3 |

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